96MHz – 400MHz Low Phase Noise XO (for 12 – 25MHz Crystals)

FEATURES

- Low phase noise output for the 96MHz to 400MHz range (-134 dBc at 10kHz offset).
- Selectable CMOS, PECL and LVDS output.
- 12 to 25MHz crystal input.
- Output Enable selector.
- 3.3V operation.
- Available in DIE (65 mil x 62 mil).

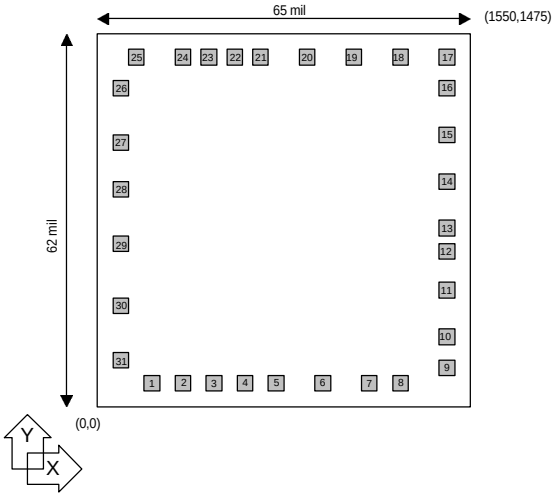
DESCRIPTIONS

The PLL602-10 is a monolithic low jitter and low phase noise (-134dBc/Hz @ 10kHz offset) XO IC Die, with CMOS, LVDS and PECL output, for 96MHz to 400MHz output range, using a low frequency crystal.
The same die can be used as a XO with output frequencies ranging from F_{XIN} x 8 to F_{XIN} x 16 thanks to selector pads allowing bonding options (see Divider Selection Table on this page). This makes the PLL602-10 ideal for a wide range of applications.

DIE SPECIFICATIONS

Name	Value
Size	62 x 65 mil
Reverse side	GND
Pad dimensions	80 micron x 80 micron
Thickness	10 mil

DIE CONFIGURATION



MULTIPLIER SELECTION

Pad #19	MULTIPLIER	OUTPUT RANGE
0	F_{XIN} x 16	192 – 400 MHz
1	F_{XIN} x 8	96 – 200 MHz

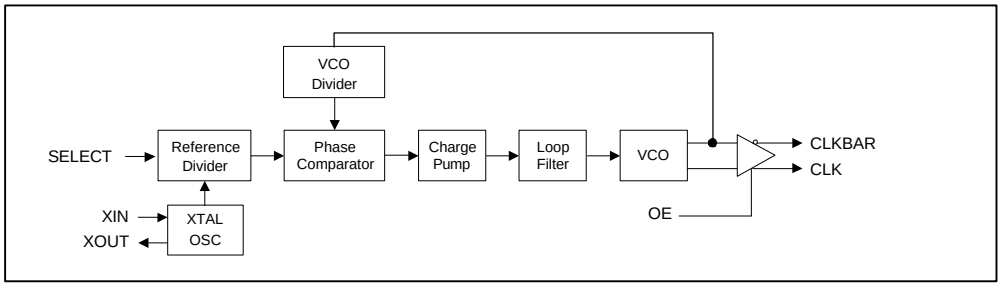
Note: Selector pad defaults to '1', wire bond to GND to set to '0'

OUTPUT SELECTION AND ENABLE

Pad #18 OUTSEL1	Pad #25 OUTSEL0	Selected Output
0	0	High Drive CMOS
0	1	Standard CMOS
1	0	PECL
1	1	LVDS

OE (Pad #30)	State
0	Tri-state
1 (Default)	Output enabled

BLOCK DIAGRAM



ELECTRICAL SPECIFICATIONS

1. Absolute Maximum Ratings

PARAMETERS	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage	V_{DD}		7	V
Input Voltage, dc	V_I	V_{SS}-0.5	V_{DD}+0.5	V
Output Voltage, dc	V_O	V_{SS}-0.5	V_{DD}+0.5	V
Storage Temperature	T_S	-65	150	°C
Ambient Operating Temperature	T_A	0	70	°C
Junction Temperature	T_J		125	°C
Lead Temperature (soldering, 10s)			260	°C
Input Static Discharge Voltage Protection			2	kV

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied.

2. Crystal Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Crystal Resonator Frequency	F_{XIN}	Parallel Fundamental Mode	12		25	MHz
Crystal Loading Rating	$C_{L\ (xtal)}$			TBD		pF
Recommended ESR	R_E	AT cut			30	Ω

3. General Electrical Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Supply Current, Dynamic (with Loaded Outputs)	I_{DD}	PECL/LVDS/CMOS			80/60/35	mA
Operating Voltage	V_{DD}		3.13		3.47	V
Output Clock Duty Cycle		@ 1.4V (CMOS) @ 1.25V (LVDS) @ Vdd – 1.3V (PECL)	45 45 45	50 50 50	55 55 55	%
Short Circuit Current				±50		mA

4. Jitter and Phase Noise specification

PARAMETERS	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Period jitter RMS	With capacitive decoupling between VDD and GND.		7		ps
Accumulated jitter RMS	With capacitive decoupling between VDD and GND. Over 10,000 cycles.		11		ps
Phase Noise relative to carrier	155MHz @100Hz offset		-90		dBc/Hz
Phase Noise relative to carrier	155MHz @1kHz offset		-114		dBc/Hz
Phase Noise relative to carrier	155MHz @10kHz offset		-134		dBc/Hz
Phase Noise relative to carrier	155MHz @100kHz offset		-134		dBc/Hz

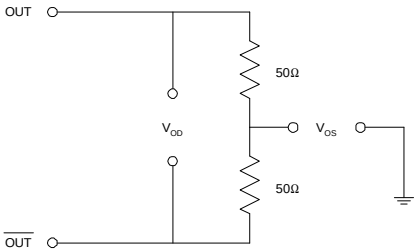
5. LVDS Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Differential Voltage	V_{OD}	R_L = 100 Ω (see figure)	247	355	454	mV
V_{DD} Magnitude Change	ΔV_{OD}		-50		50	mV
Output High Voltage	V_{OH}			1.4	1.6	V
Output Low Voltage	V_{OL}		0.9	1.1		V
Offset Voltage	V_{OS}		1.125	1.2	1.375	V
Offset Magnitude Change	ΔV_{OS}		0	3	25	mV
Power-off Leakage	I_{OXD}	V_{out} = V_{DD} or GND, V_{DD} = 0V		±1	±10	uA
Output Short Circuit Current	I_{OSD}			-5.7	-8	mA

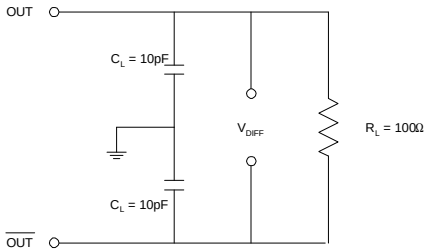
6. LVDS Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Differential Clock Rise Time	t_r	R_L = 100 Ω, C_L = 10 pF (see figure)	0.2	0.7	1.0	ns
Differential Clock Fall Time	t_f		0.2	0.7	1.0	ns

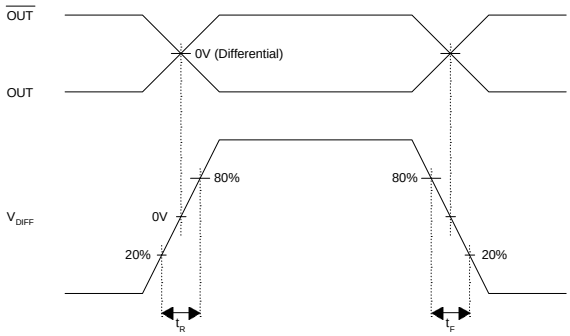
LVDS Levels Test Circuit



LVDS Switching Test Circuit



LVDS Transistion Time Waveform



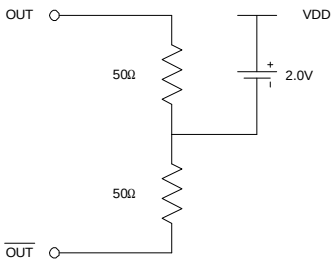
7. PECL Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
Output High Voltage	V_{OH}	R_L = 50 Ω to (V_{DD} – 2V) (see figure)	V_{DD} – 1.025		V
Output Low Voltage	V_{OL}			V_{DD} – 1.620	V

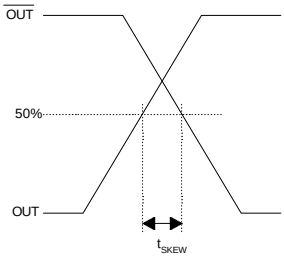
8. PECL Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Clock Rise Time	t_r	@20/80% - PECL		0.6	1.5	ns
Clock Fall Time	t_f	@80/20% - PECL		0.5	1.5	ns

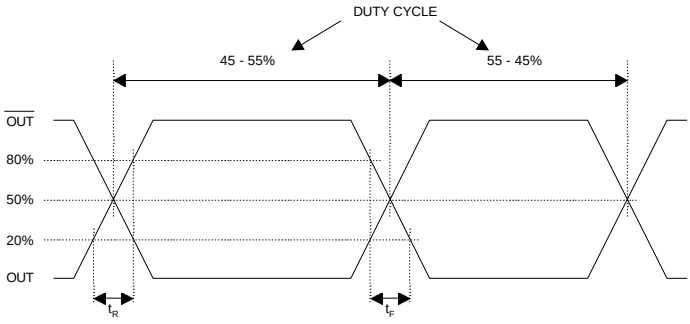
PECL Levels Test Circuit



PECL Output Skew



PECL Transistion Time Waveform



PAD ASSIGNMENT

Pad #	Name	X (µm)	Y (µm)
1	GND	248	109
2	GND	361	109
3	GND	473	109
4	GND	587	109
5	GND	702	109
6	N/C	874	109
7	GND	1042	109
8	GNDBUF	1171	109
9	CMOS	1400	125
10	LVDS	1400	259
11	PECL	1400	476
12	VDDBUF	1400	616
13	VDDBUF	1400	716
14	PECLB	1400	871
15	LVDSB	1400	1089
16	CMOSB	1400	1227
17	GNDBUF	1389	1365
18	OUTSEL1	1232	1365
19	FSEL	1042	1365
20	N/C	854	1365
21	VDD	659	1365
22	VDD	559	1365
23	VDD	459	1365
24	VDD	358	1365
25	OUTSEL0	194	1365
26	XIN	109	1223
27	XOUT	109	1017
28	N/C	109	858
29	N/C	109	646
30	OE	109	397
31	N/C	109	181

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ORDERING INFORMATION

For part ordering, please contact our Sales Department:

47745 Fremont Blvd., Fremont, CA 94538, USA
Tel: (510) 492-0990 Fax: (510) 492-0991

PART NUMBER

The order number for this device is a combination of the following:
Device number, Package type and Operating temperature range

PLL602-10 D C

PART NUMBER

TEMPERATURATRE
C=COMMERCIAL
M=MILITARY
I=INDUSTRAL

PACKAGE TYPE
D=DIE

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